

# Digital transistors (built-in resistors)

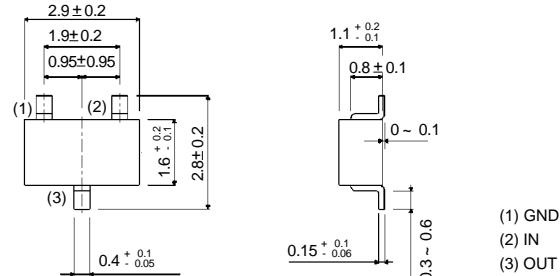
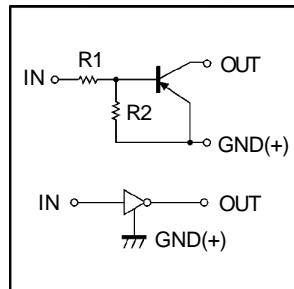
- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

- Structure

PNP digital transistor (with built-in resistors)

- Equivalent circuit



EIAJ: SC—59

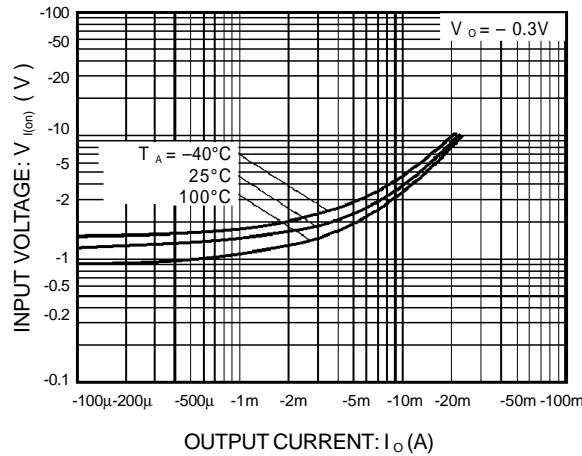
- Absolute maximum ratings( $T_a = 25^\circ C$ )

Parameter	symbol	limits		unit
Supply voltage	$V_{cc}$	- 50		V
Input voltage	$V_{in}$	-40~+10		V
Output current	$I_o$	-30		mA
	$I_{C(\text{Max.})}$	-100		
Power dissipation	$P_d$	200		mW
Junction temperature	$T_j$	150		°C
Storage temperature	$T_{sig}$	-55~+150		°C

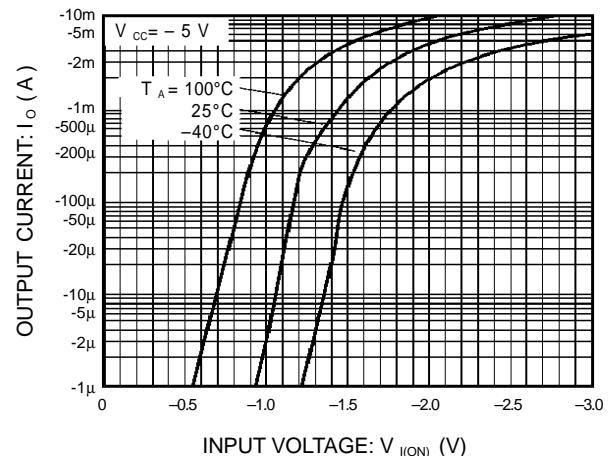
- Electrical characteristics( $T_a = 25^\circ C$ )

Parameter	symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(\text{off})}$	—	—	-0.5	V	$V_{cc} = -5V, I_o = -100\mu A$
	$V_{I(\text{on})}$	-3.0	—	—		$V_o = -0.3V, I_o = -2mA$
Output Voltage	$V_{O(\text{on})}$	—	-0.1	-0.3	V	$I_o / I_i = -10mA / -0.5mA$
Input current	$I_i$	—	—	-0.18	mA	$V_i = -5V$
Output current	$I_{O(\text{off})}$	—	—	-0.5	μA	$V_{cc} = -50V, V_i = 0V$
DC current gain	$G_i$	68	—	—	—	$V_o = -5V, I_o = -5mA$
Input resistance	$R_i$	32.9	47	61.1	KΩ	—
Resistance ratio	$R_2 / R_1$	0.8	1	1.2	—	—
Transition frequency	$f_T$	—	250	—	MHz	$V_{ce} = -10V, I_E = 5mA, f = 100MHz^*$

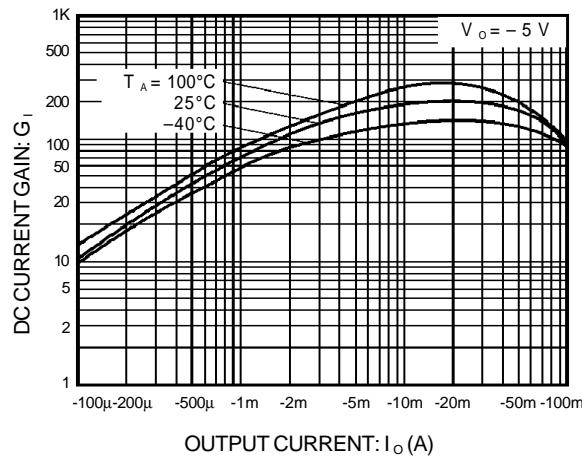
\*Transition frequency of the device

**DTA144EKA**
**ELECTRICAL CHARACTERISTIC CURVES**


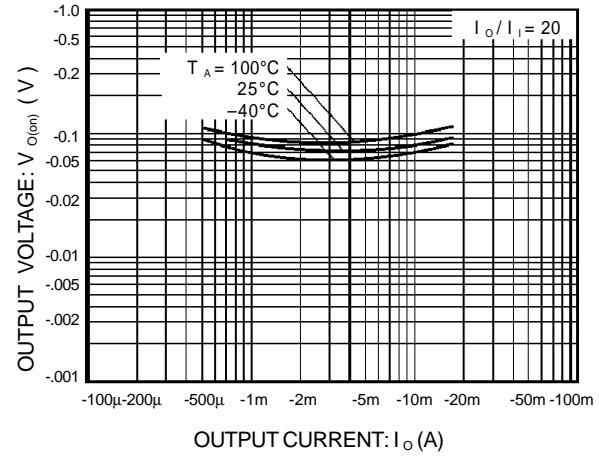
**Figure 1. Input voltage vs.output current  
(ON characteristics)**



**Figure 2. Output current vs.input voltage  
(OFF characteristics)**



**Figure 3. DC current gain vs.output current**



**Figure 4. Output voltage vs.output current**